**Product data sheet** 

# 1. General description

NPN low  $V_{CEsat}$  transistor in a medium power and flat lead SOT89 (SC-62) Surface-Mounted Device (SMD) plastic package.

PNP complement: PBSS4041PX-Q

### 2. Features and benefits

- Very low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain (h<sub>FE</sub>) at high I<sub>C</sub>
- High energy efficiency due to less heat generation
- Qualified according to AEC-Q101 and recommended for use in automotive applications

# 3. Applications

- Loadswitch
- · Battery-driven devices
- Power management
- Charging circuits
- · Power switches (e.g. motors, fans)

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	60	V
I <sub>C</sub>	collector current		-	-	6.2	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	-	15	Α
R <sub>CEsat</sub>	collector-emitter saturation resistance	$I_C$ = 4 A; $I_B$ = 400 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	18	35	mΩ

# 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Е	emitter		С
2	С	collector		в—
3	В	base	3 2 1 SOT89	E sym042



# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package	je				
	Name	Description	Version			
PBSS4041NX-Q		plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	<u>SOT89</u>			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS4041NX-Q	%6F

[1] % = placeholder for manufacturing site code

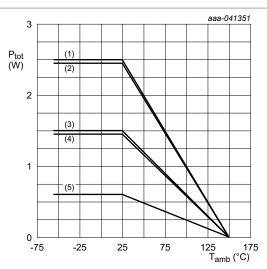
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	60	V
$V_{CEO}$	collector-emitter voltage	open base		-	60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	5	V
Ic	collector current			-	6.2	Α
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	15	А
I <sub>B</sub>	base current			-	1	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	600	mW
			[2]	-	1.5	W
			[3]	-	1.45	W
			[4]	-	2.45	W
			[5]	-	2.5	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

- 1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, 4-layer, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, 4-layer, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [5] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, single-sided, 35 µm copper, tin-plated and standard footprint.



- (1) Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, 35 μm copper, standard footprint.
- (2) FR4 PCB, 4-layer copper, 1 cm<sup>2</sup>.
- (3) FR4 PCB, single-sided, 35 μm copper, 6 cm<sup>2</sup>.
- (4) FR4 PCB, 4-layer copper, standard footprint.
- (5) FR4 PCB, single-sided, 35µm copper, standard footprint.

Fig. 1. Power derating curves

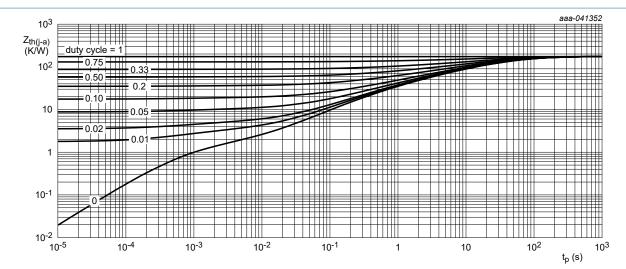
### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uig-a)		junction to ambient	[1]	-	-	208	K/W
	junction to ambient		[2]	-	-	83	K/W
			[3]	-	-	86	K/W
			[4]	-	-	51	K/W
			[5]	-	-	50	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	-	20	K/W

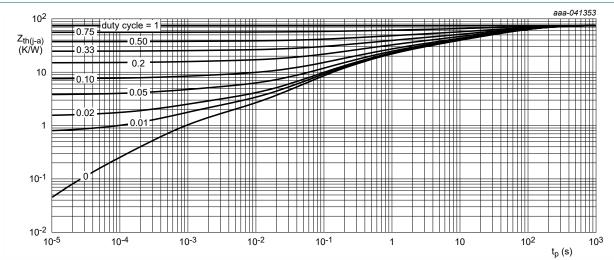
- [1] Device mounted on an FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, 4-layer, tin-plated and standard footprint.
- [4] Device mounted on an FR4 PCB, 4-layer, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [5] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, single-sided, 35 μm copper, tin-plated and standard footprint.

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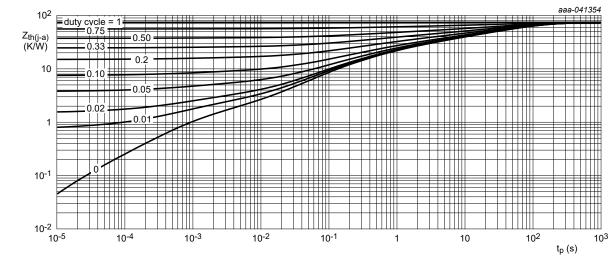
FR4 PCB, single-sided, 35 µm copper, tin-plated and standard footprint

Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



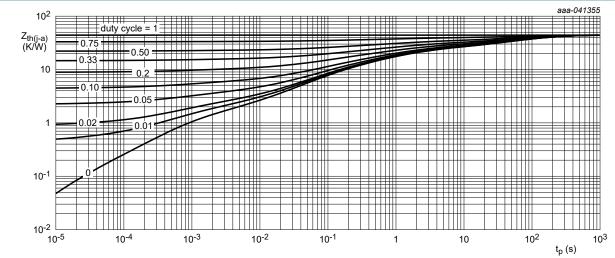
FR4 PCB, single-sided, 35 µm copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



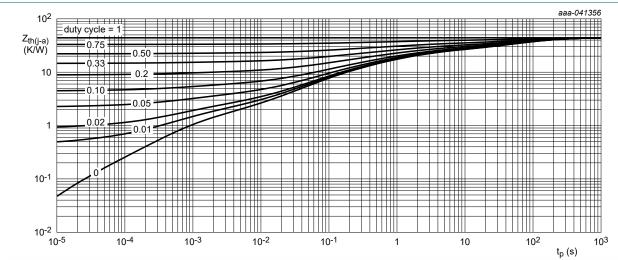
FR4 PCB, 4-layer 35 µm copper, tin-plated and standard footprint.

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, 4-layer 35  $\mu m$  copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, single-sided, 35 µm copper, tin-plated and standard footprint.

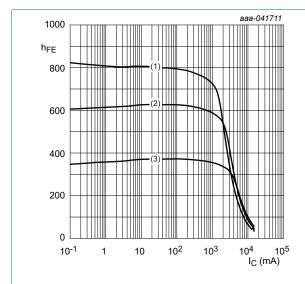
Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

# 10. Characteristics

#### Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$J_{(BR)CBO}$	collector-base breakdown voltage	$I_C = 100 \ \mu A; I_E = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	60	-	-	V
/ <sub>(BR)CEO</sub>	collector-emitter breakdown voltage	$I_C = 10 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	60	-	-	V
/ <sub>(BR)EBO</sub>	emitter-base breakdown voltage	$I_E = 100 \ \mu A; I_C = 0 \ A; T_{amb} = 25 \ ^{\circ}C$	5	-	-	V
СВО	collector-base cut-off	V <sub>CB</sub> = 60 V; I <sub>E</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
	current	V <sub>CB</sub> = 60 V; I <sub>E</sub> = 0 A; T <sub>j</sub> = 150 °C	-	-	50	μΑ
CES	collector-emitter cut-off current	V <sub>CE</sub> = 48 V; V <sub>BE</sub> = 0 V; T <sub>amb</sub> = 25 °C	-	-	100	nA
EBO	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	100	nA
) <sub>FE</sub>	DC current gain	$V_{CE}$ = 2 V; $I_{C}$ = 0.5 A; pulsed; $t_{p}$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	300	525	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 1 A; pulsed; $t_{p} \le 300 \ \mu s$ ; δ ≤ 0.02; $T_{amb}$ = 25 °C	300	510	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 2 A; pulsed; $t_{p} \le 300 \ \mu s$ ; $\delta \le 0.02$ ; $T_{amb}$ = 25 °C	250	470	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 4 A; pulsed; $t_{p} \le 300 \ \mu s$ ; δ ≤ 0.02; $T_{amb}$ = 25 °C	150	280	-	
		$V_{CE}$ = 2 V; $I_{C}$ = 6 A; pulsed; $t_{p} \le 300 \ \mu s$ ; δ ≤ 0.02; $T_{amb}$ = 25 °C	75	170	-	
/ <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C$ = 1 A; $I_B$ = 10 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	50	80	mV
		$I_C$ = 1 A; $I_B$ = 50 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	30	50	mV
		$I_C$ = 2 A; $I_B$ = 40 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	60	145	mV
		$I_C$ = 4 A; $I_B$ = 40 mA; pulsed; $t_p \le$ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	150	320	mV
		$I_C$ = 4 A; $I_B$ = 200 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	80	150	mV
		$I_C$ = 6 A; $I_B$ = 300 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	120	210	mV
CEsat	collector-emitter saturation resistance	$I_C$ = 4 A; $I_B$ = 400 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	18	35	mΩ
/ <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = 1 A; $I_B$ = 100 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	0.83	0.9	V
		$I_C$ = 4 A; $I_B$ = 400 mA; pulsed; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	1	1.05	V
/ <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE}$ = 2 V; $I_{C}$ = 2 A; pulsed; $t_{p} \le 300 \ \mu s$ ; δ ≤ 0.02; $T_{amb}$ = 25 °C	-	0.77	0.85	V

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t <sub>d</sub>	delay time	V <sub>CC</sub> = 12.5 V; I <sub>C</sub> = 1 A; I <sub>Bon</sub> = 50 mA;	-	35	-	ns
t <sub>r</sub>	rise time	I <sub>Boff</sub> = -50 mA; T <sub>amb</sub> = 25 °C	-	50	-	ns
t <sub>on</sub>	turn-on time		-	85	-	ns
ts	storage time		-	700	-	ns
t <sub>f</sub>	fall time		-	120	-	ns
t <sub>off</sub>	turn-off time		-	820	-	ns
f <sub>T</sub>	transition frequency	$V_{CE}$ = 10 V; $I_{C}$ = 100 mA; f = 100 MHz; $T_{amb}$ = 25 °C	-	125	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB}$ = 10 V; $I_{E}$ = 0 A; $i_{e}$ = 0 A; $f$ = 1 MHz; $T_{amb}$ = 25 °C	-	30	-	pF



V<sub>CE</sub> = 2 V (1) T<sub>amb</sub> = 100 °C (2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -55 °C

Fig. 7. DC current gain as a function of collector current; typical values

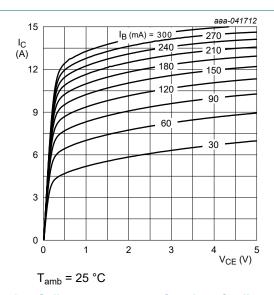
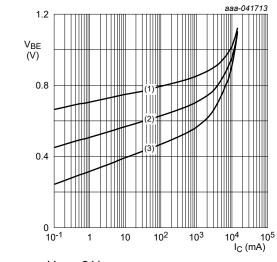


Fig. 8. Collector current as a function of collectoremitter voltage; typical values



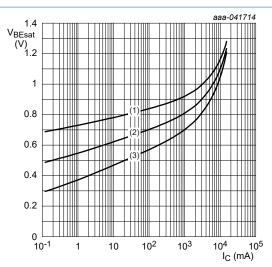
 $V_{CE} = 2 V$ 

 $(1) T_{amb} = -55 °C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 9. Base-emitter voltage as a function of collector current; typical values



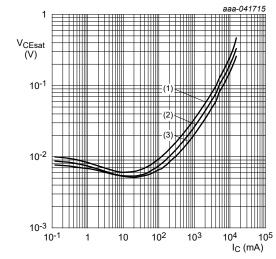
 $I_C/I_B = 20$ 

(1)  $T_{amb} = -55 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig. 10. Base-emitter saturation voltage as a function of collector current; typical values

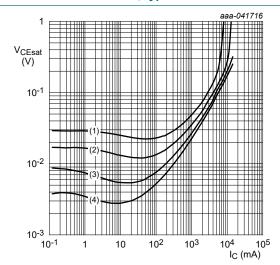


 $I_{\rm C}/I_{\rm B} = 20$ 

(1)  $T_{amb} = 100 \, ^{\circ}C$ 

(2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = -55 °C

Fig. 11. Collector-emitter saturation voltage as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

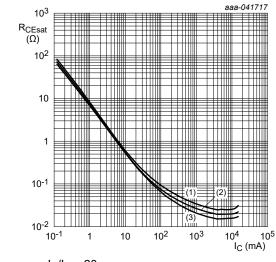
(1)  $I_C/I_B = 100$ 

 $(2) I_{C} / I_{B} = 50$ 

(3)  $I_C/I_B = 20$ 

 $(4) I_{\rm C} / I_{\rm B} = 10$ 

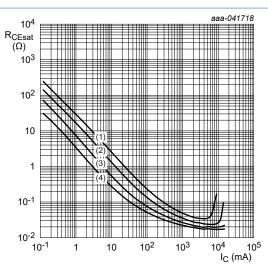
Fig. 12. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_C/I_B = 20$ (1)  $T_{amb} = 100 \, ^{\circ}C$ 

(2)  $T_{amb} = 25 \,^{\circ}\text{C}$ (3)  $T_{amb} = -55 \,^{\circ}\text{C}$ 

Fig. 13. Collector-emitter saturation resistance as a function of collector current; typical values

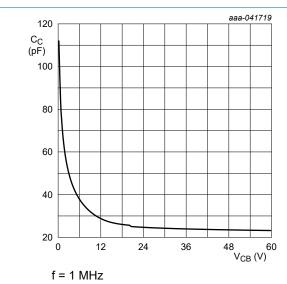


 $T_{amb}$  = 25 °C

 $(1) I_{\rm C} / I_{\rm B} = 100$ 

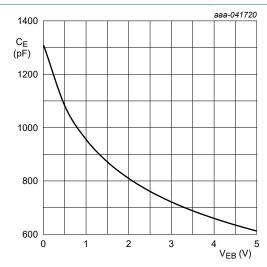
(2)  $I_C/I_B = 50$ (3)  $I_C/I_B = 20$ (4)  $I_C/I_B = 10$ 

Fig. 14. Collector-emitter saturation resistance as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

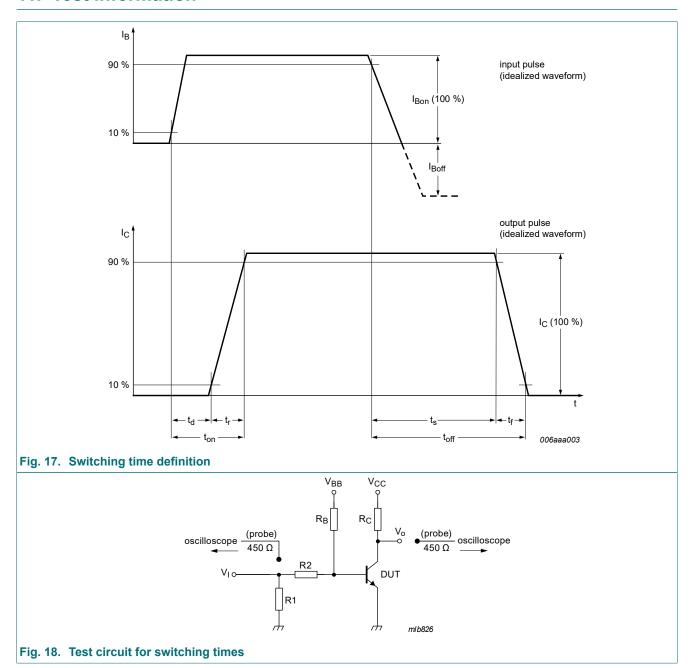
base voltage; typical value



f = 1 MHz $T_{amb}$  = 25 °C

Fig. 15. Collector capacitance as a function of collector- Fig. 16. Emitter capacitance as a function of emitterbase voltage; typical value

## 11. Test information

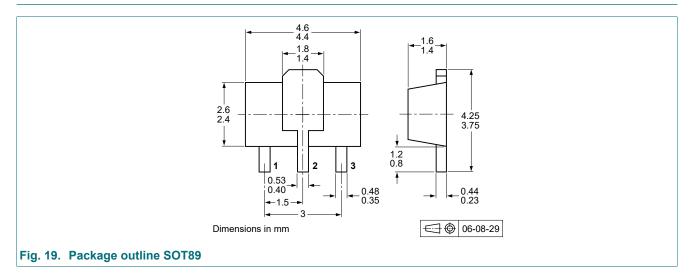


## **Quality information**

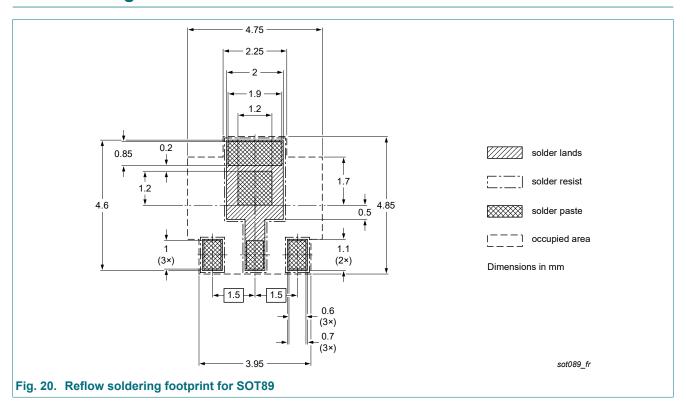
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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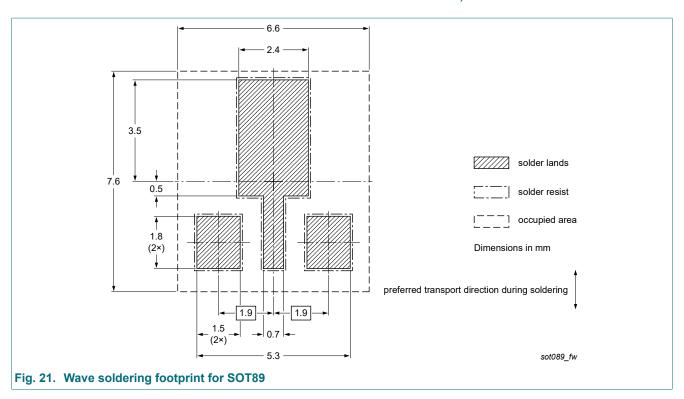
# 12. Package outline



# 13. Soldering



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# 14. Revision history

#### **Table 8. Revision history**

Tuble of Nevicien metery							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS4041NX-Q v.2	20250117	Product data sheet	-	PBSS4041NX-Q v.1			
Modifications:	New graphics and values are added.						
PBSS4041NX-Q v.1	20240206	Product data sheet	-	-			

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 17 January 2025

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